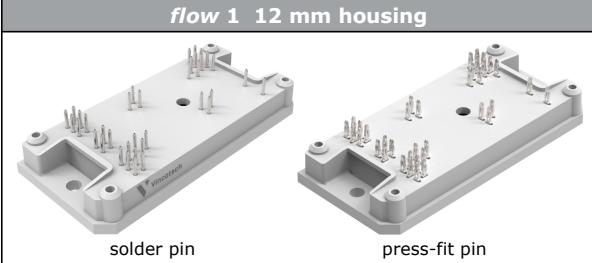
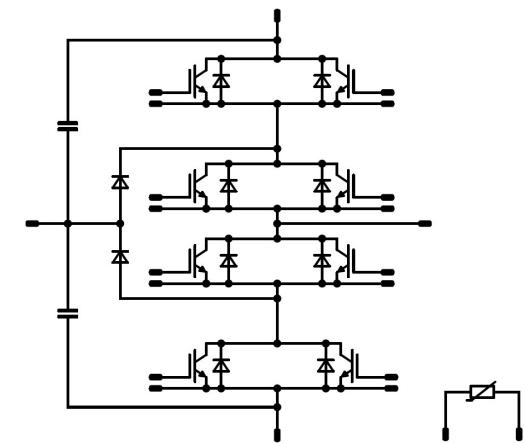




10-FY07NPA150SM01-L364F08
10-PY07NPA150SM01-L364F08Y
datasheet

Vincotech

flowNPC 1		1200 V / 150 A
Features		
<ul style="list-style-type: none">• NPC inverter topology• Optimized for real power• LVRT and Reactive power capability• High-speed IGBT in the outer switches• Low drop IGBT (L5) in the inner switches• Integrated NTC• Low inductive design with integrated DC capacitor• flow 1 12mm package		
Target applications		flow 1 12 mm housing
<ul style="list-style-type: none">• Solar inverter• UPS		 <p>solder pin press-fit pin</p>
Types		Schematic
<ul style="list-style-type: none">• 10-FY07NPA150SM01-L364F08• 10-PY07NPA150SM01-L364F08Y		

Maximum Ratings

$T_j = 25^\circ\text{C}$, unless otherwise specified

Parameter	Symbol	Condition	Value	Unit
Buck Switch				
Collector-emitter voltage	V_{CES}		650	V
Collector current	I_C	$T_j = T_{jmax}$ $T_s = 80^\circ\text{C}$	83	A
Repetitive peak collector current	I_{CRM}	t_p limited by T_{jmax}	450	A
Total power dissipation	P_{tot}	$T_j = T_{jmax}$ $T_s = 80^\circ\text{C}$	128	W
Gate-emitter voltage	V_{GES}		± 20	V
Maximum junction temperature	T_{jmax}		175	$^\circ\text{C}$



Vincotech

Maximum Ratings

$T_j = 25^\circ\text{C}$, unless otherwise specified

Parameter	Symbol	Condition	Value	Unit
-----------	--------	-----------	-------	------

Buck Diode

Peak repetitive reverse voltage	V_{RRM}		650	V
Continuous (direct) forward current	I_F	$T_j = T_{jmax}$ $T_s = 80^\circ\text{C}$	68	A
Total power dissipation	P_{tot}	$T_j = T_{jmax}$ $T_s = 80^\circ\text{C}$	112	W
Maximum junction temperature	T_{jmax}		175	$^\circ\text{C}$

Out. Boost Switch

Collector-emitter voltage	V_{CES}		650	V
Collector current	I_C	$T_j = T_{jmax}$ $T_s = 80^\circ\text{C}$	150	A
Repetitive peak collector current	I_{CRM}	t_p limited by T_{jmax}	450	A
Total power dissipation	P_{tot}	$T_j = T_{jmax}$ $T_s = 80^\circ\text{C}$	164	W
Gate-emitter voltage	V_{GES}		± 20	V
Maximum junction temperature	T_{jmax}		175	$^\circ\text{C}$

Out. Boost Diode

Peak repetitive reverse voltage	V_{RRM}		650	V
Continuous (direct) forward current	I_F	$T_j = T_{jmax}$ $T_s = 80^\circ\text{C}$	82	A
Repetitive peak forward current	I_{FRM}		200	A
Total power dissipation	P_{tot}	$T_j = T_{jmax}$ $T_s = 80^\circ\text{C}$	106	W
Maximum junction temperature	T_{jmax}		175	$^\circ\text{C}$

Out. Boost Inverse Diode

Peak repetitive reverse voltage	V_{RRM}		650	V
Continuous (direct) forward current	I_F	$T_j = T_{jmax}$ $T_s = 80^\circ\text{C}$	100	A
Repetitive peak forward current	I_{FRM}		200	A
Total power dissipation	P_{tot}	$T_j = T_{jmax}$ $T_s = 80^\circ\text{C}$	203	W
Maximum junction temperature	T_{jmax}		175	$^\circ\text{C}$

DC Link Capacitor

Maximum DC voltage	V_{MAX}		630	V
Operation Temperature	T_{op}		-55...+125	$^\circ\text{C}$



Maximum Ratings

$T_j = 25 \text{ } ^\circ\text{C}$, unless otherwise specified

Parameter	Symbol	Condition	Value	Unit
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Module Properties

Thermal Properties

Storage temperature	T_{stg}		-40...+125	°C
Operation temperature under switching condition	T_{jop}		-40...($T_{\text{jmax}} - 25$)	°C

Isolation Properties

Isolation voltage	V_{isol}	DC Test Voltage*	$t_p = 2 \text{ s}$	6000	V
		AC Voltage	$t_p = 1 \text{ min}$	2500	V
Creepage distance				min. 12,7	mm
Clearance		solder pin \ press-fit pin		8,07 \ 7,86	mm
Comparative Tracking Index	CTI			> 200	

*100 % tested in production



Vincotech

Characteristic Values

Parameter	Symbol	Conditions						Value			Unit
			V_{GE} [V]	V_{CE} [V]	I_c [A]	I_D [A]	T_1 [°C]	Min	Typ	Max	
			V_{GS} [V]	V_{DS} [V]	I_F [A]	I_F [A]					

Buck Switch

Static

Gate-emitter threshold voltage	$V_{GE(\text{th})}$	$V_{GE} = V_{CE}$			0,0015	25	3,3	4	4,7	V
Collector-emitter saturation voltage	$V_{CE\text{sat}}$		15		150	25 125 150		1,70 1,88 1,93	2,22	V
Collector-emitter cut-off current	I_{CES}		0	650		25			80	µA
Gate-emitter leakage current	I_{GES}		20	0		25			240	nA
Internal gate resistance	r_g							none		Ω
Input capacitance	C_{ies}	$f = 1 \text{ Mhz}$	0	25	25	25		8600		pF
Output capacitance	C_{oes}							150		
Reverse transfer capacitance	C_{res}							32		
Gate charge	Q_g		15	520	150	25		332		nC

Thermal

Thermal resistance junction to sink	$R_{th(j-s)}$	$\lambda_{\text{paste}} = 3,4 \text{ W/mK}$ (PSX)						0,74		K/W
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Dynamic

Turn-on delay time	$t_{d(on)}$	$R_{gon} = 2 \Omega$ $R_{goff} = 2 \Omega$	-5 / 15	700	90	25		46		ns
Rise time	t_r					125		46		
						150		46		
Turn-off delay time	$t_{d(off)}$					25		11		
Fall time	t_f	$Q_{rFWD} = 1,5 \mu\text{C}$ $Q_{rFWD} = 3,7 \mu\text{C}$ $Q_{rFWD} = 4,8 \mu\text{C}$	700	90	125		13			mWs
Turn-on energy (per pulse)	E_{on}				150		14			
					25		130			
Fall time	t_f				125		147			
		$Q_{rFWD} = 1,5 \mu\text{C}$ $Q_{rFWD} = 3,7 \mu\text{C}$ $Q_{rFWD} = 4,8 \mu\text{C}$	700	90	150		152			
Turn-on energy (per pulse)	E_{on}				25		7			
					125		7			
Turn-off energy (per pulse)	E_{off}				150		7			
		$Q_{rFWD} = 1,5 \mu\text{C}$ $Q_{rFWD} = 3,7 \mu\text{C}$ $Q_{rFWD} = 4,8 \mu\text{C}$	700	90	25		0,562			mWs
					125		0,931			
					150		1,051			
					25		0,361			



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Characteristic Values

Parameter	Symbol	Conditions						Value			Unit
			V_{GE} [V]	V_{CE} [V]	I_c [A]	I_D [A]	T_j [°C]	Min	Typ	Max	
			V_{GS} [V]	V_{DS} [V]	I_F [A]	I_F [A]					

Buck Diode

Static

Forward voltage	V_F				100	25 125		2,50 2,19	2,6	V
Reverse leakage current	I_R			650		25			20	µA

Thermal

Thermal resistance junction to sink	$R_{th(j-s)}$	$\lambda_{paste} = 3,4 \text{ W/mK}$ (PSX)						0,85		K/W
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Dynamic

Peak recovery current	I_{RRM}	$di/dt = 7366 \text{ A/}\mu\text{s}$ $di/dt = 6200 \text{ A/}\mu\text{s}$ $di/dt = 6600 \text{ A/}\mu\text{s}$	-5 / 15	700	90	25		88		A
Reverse recovery time	t_{rr}					125		121		
Recovered charge	Q_r					150		131		
Reverse recovered energy	E_{rec}					25		22		ns
Peak rate of fall of recovery current	$(di_{rf}/dt)_{max}$					125		70		





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Characteristic Values

Parameter	Symbol	Conditions						Value			Unit
		V_{GE} [V]	V_{CE} [V]	I_c [A]	I_D [A]	T_j [°C]	Min	Typ	Max		
		V_{GS} [V]	V_{DS} [V]	I_F [A]	I_F [A]						

Out. Boost Switch

Static

Gate-emitter threshold voltage	$V_{GE(th)}$	$V_{GE} = V_{CE}$			0,002	25	4,2	5	5,8	V
Collector-emitter saturation voltage	V_{CESat}		15		150	25 150		1,10 1,09	1,45	V
Collector-emitter cut-off current	I_{CES}		0	650		25			80	µA
Gate-emitter leakage current	I_{GES}		20	0		25			200	nA
Internal gate resistance	r_g							none		Ω
Input capacitance	C_{ies}	$f = 1 \text{ MHz}$	0	25	25			23250		pF
Reverse transfer capacitance	C_{res}									
Gate charge	Q_g		15	520	150	25		872		nC

Thermal

Thermal resistance junction to sink	$R_{th(j-s)}$	$\lambda_{\text{paste}} = 3,4 \text{ W/mK}$ (PSX)						0,58		K/W
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Dynamic

Turn-on delay time	$t_{d(on)}$	$R_{gon} = 2 \Omega$ $R_{goff} = 2 \Omega$	-5 / 15	700	90	25		95		ns
Rise time	t_r					125		94		
						150		94		
Turn-off delay time	$t_{d(off)}$					25		7		
Fall time	t_f					125		9		
						150		9		
Turn-on energy (per pulse)	E_{on}	$Q_{rFWD} = 3,2 \mu\text{C}$ $Q_{rFWD} = 5,9 \mu\text{C}$ $Q_{rFWD} = 6,7 \mu\text{C}$				25		356		mWs
						125		397		
						150		412		
Fall time	t_f					25		74		
						125		73		
						150		65		
Turn-off energy (per pulse)	E_{off}					25		0,450		
						125		0,682		
						150		0,849		
						25		4,431		
						125		6,677		
						150		7,032		



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Characteristic Values

Parameter	Symbol	Conditions						Value			Unit
			V_{GE} [V]	V_{CE} [V]	I_c [A]	I_D [A]	T_1 [°C]	Min	Typ	Max	
			V_{GS} [V]	V_{DS} [V]	I_F [A]	I_F [A]					

Out. Boost Diode

Static

Forward voltage	V_F				100	25 125 150		1,50 1,43 1,40	1,77		V
Reverse leakage current	I_R			650		25			5,3		µA

Thermal

Thermal resistance junction to sink	$R_{th(j-s)}$	$\lambda_{paste} = 3,4 \text{ W/mK}$ (PSX)						0,90		K/W
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Dynamic

Peak recovery current	I_{RRM}	$di/dt = 8581 \text{ A/}\mu\text{s}$ $di/dt = 8320 \text{ A/}\mu\text{s}$ $di/dt = 7500 \text{ A/}\mu\text{s}$	-5 / 15	700	90	25		103		A
Reverse recovery time	t_{rr}					125		130		
Recovered charge	Q_r					150		137		
Reverse recovered energy	E_{rec}					25		51		ns
						125		86		
Peak rate of fall of recovery current	$(di_{rf}/dt)_{max}$					150		94		
						25		3,178		
						125		5,859		
						150		6,736		µC
						25		0,763		
						125		1,449		mWs
						150		1,630		
						25		2631		
						125		2254		A/µs
						150		2303		

Out. Boost Inverse Diode

Static

Forward voltage	V_F				100	25 150	1,18 1,57	1,77 1,57	1,82		V
Reverse leakage current	I_R			650		25			1,2		µA

Thermal

Thermal resistance junction to sink	$R_{th(j-s)}$	$\lambda_{paste} = 3,4 \text{ W/mK}$ (PSX)						0,47		K/W
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DC Link Capacitor

Capacitance	C							200		nF
Tolerance							-10		+10	%
Dissipation factor		$f = 1 \text{ kHz}$				25			2,5	%



Vincotech

Characteristic Values

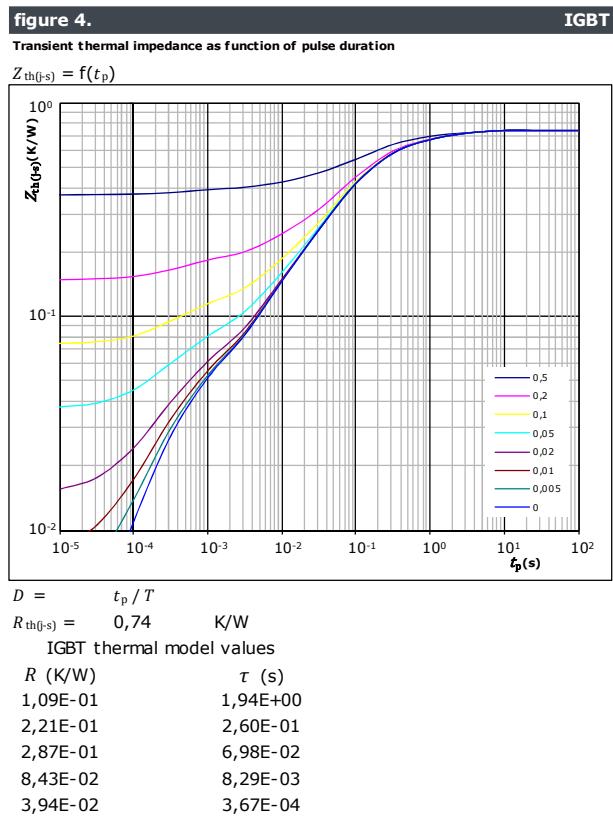
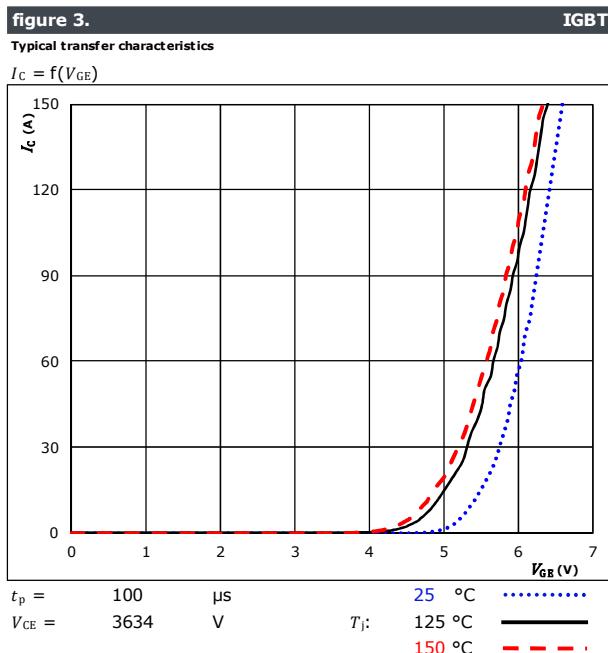
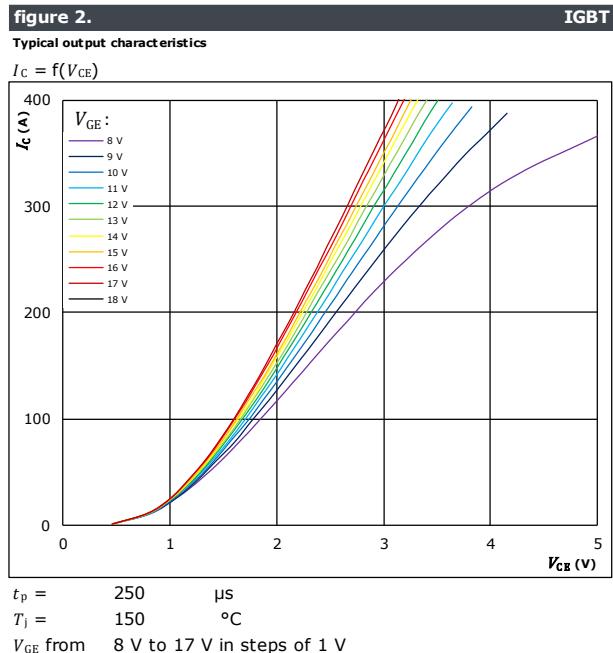
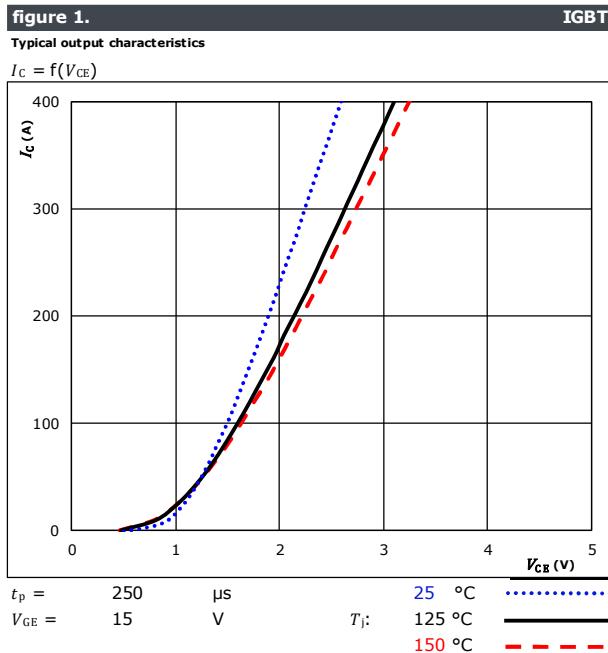
Parameter	Symbol	Conditions						Value			Unit		
			V_{GE} [V]	V_{CE} [V]	I_c [A]	V_{GS} [V]	V_{DS} [V]	I_D [A]	T_1 [°C]	I_F [A]	Min	Typ	Max

Thermistor

Rated resistance	R					25		22			kΩ
Deviation of R_{100}	$\Delta R/R$	$R_{100} = 1484 \Omega$				100		-5		5	%
Power dissipation	P					25		5			mW
Power dissipation constant						25		1,5			mW/K
B-value	$B_{(25/50)}$	Tol. ±1 %				25		3962			K
B-value	$B_{(25/100)}$	Tol. ±1 %				25		4000			K
Vincotech NTC Reference										I	



Buck Switch Characteristics

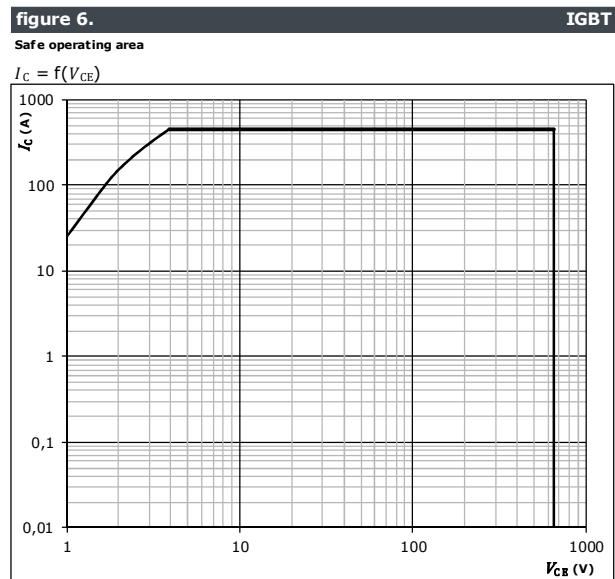
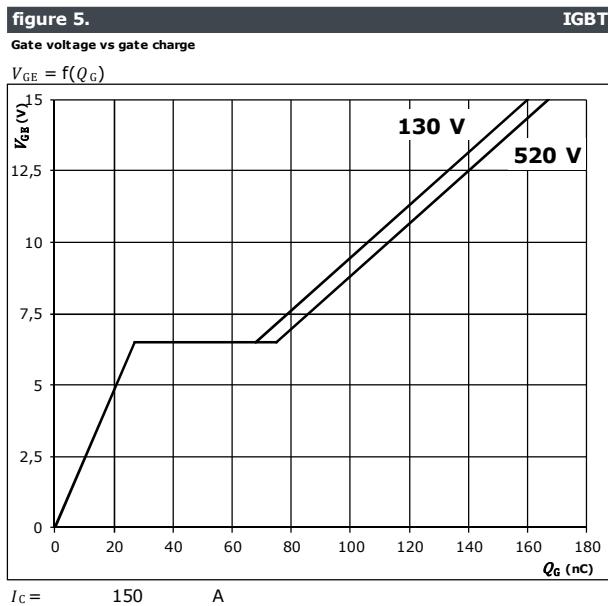




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10-PY07NPA150SM01-L364F08Y**
datasheet

Buck Switch Characteristics

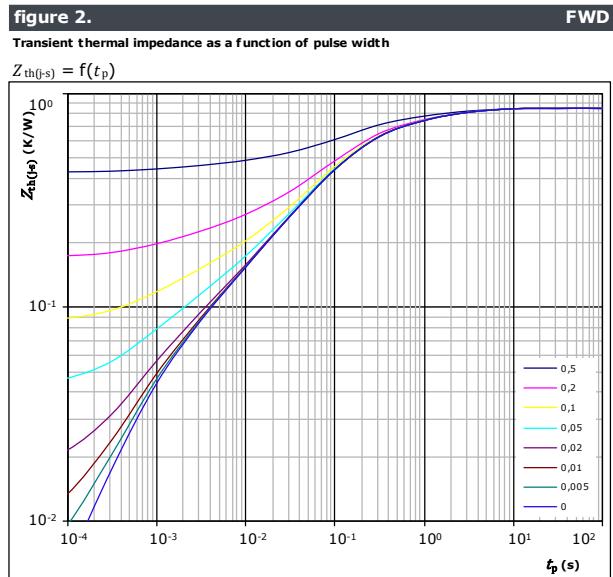
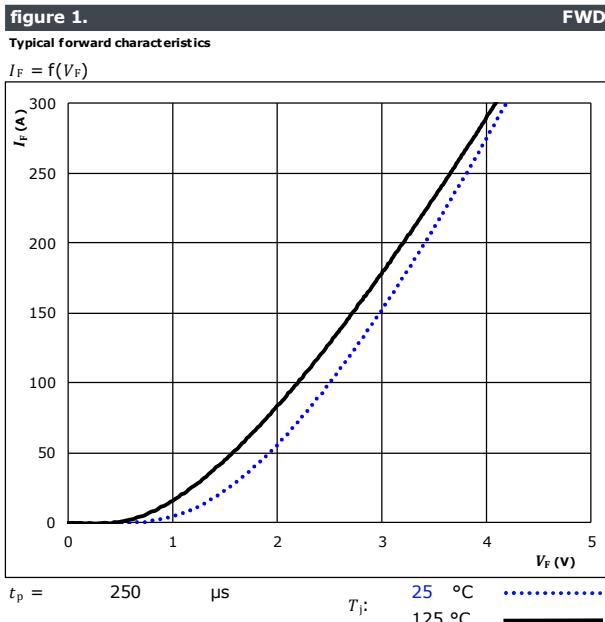




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**10-FY07NPA150SM01-L364F08
10-PY07NPA150SM01-L364F08Y**
datasheet

Buck Diode Characteristics



FWD thermal model values

R (K/W)	τ (s)
9,18E-02	3,34E+00
1,92E-01	6,05E-01
3,65E-01	1,19E-01
1,13E-01	2,58E-02
5,25E-02	4,68E-03
3,80E-02	8,67E-04

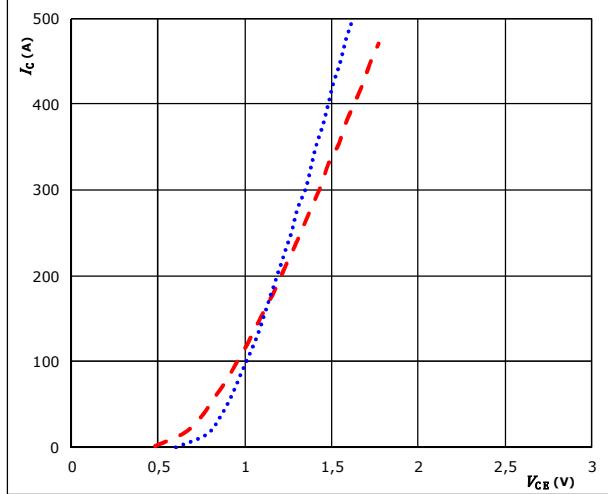


Out. Boost Switch Characteristics

figure 1. IGBT

Typical output characteristics

$$I_C = f(V_{CE})$$

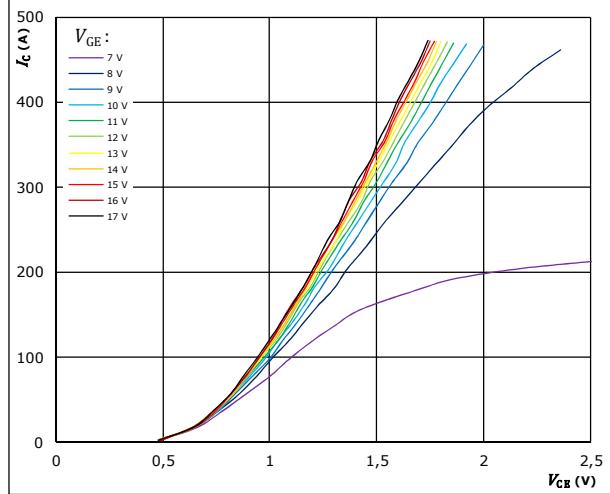


$t_p = 250 \mu\text{s}$ $T_j: 25^\circ\text{C}$
 $V_{GE} = 15 \text{ V}$ $T_j: 150^\circ\text{C}$ -----

figure 2. IGBT

Typical output characteristics

$$I_C = f(V_{CE})$$

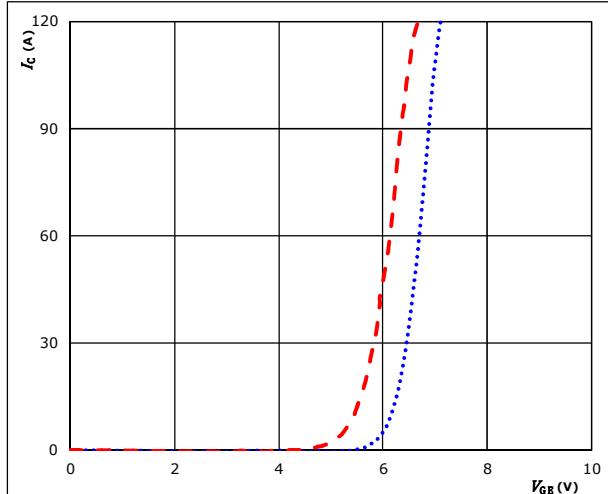


$t_p = 250 \mu\text{s}$
 $T_j = 150^\circ\text{C}$
 V_{GE} from 7 V to 17 V in steps of 1 V

figure 3. IGBT

Typical transfer characteristics

$$I_C = f(V_{GE})$$

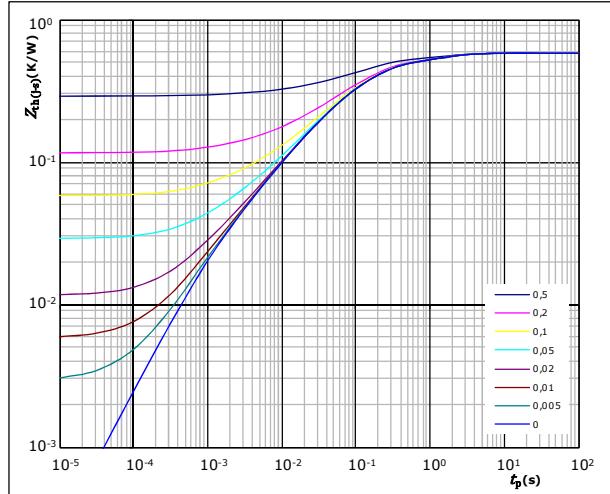


$t_p = 100 \mu\text{s}$ $T_j: 25^\circ\text{C}$
 $V_{CE} = 10 \text{ V}$ $T_j: 150^\circ\text{C}$ -----

figure 4. IGBT

Transient thermal impedance as function of pulse duration

$$Z_{th(j-s)} = f(t_p)$$



$D = t_p / T$
 $R_{th(j-s)} = 0,58 \text{ K/W}$

IGBT thermal model values

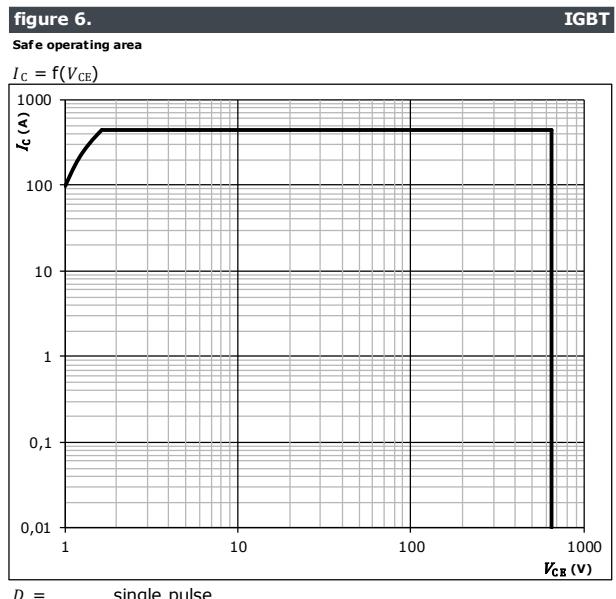
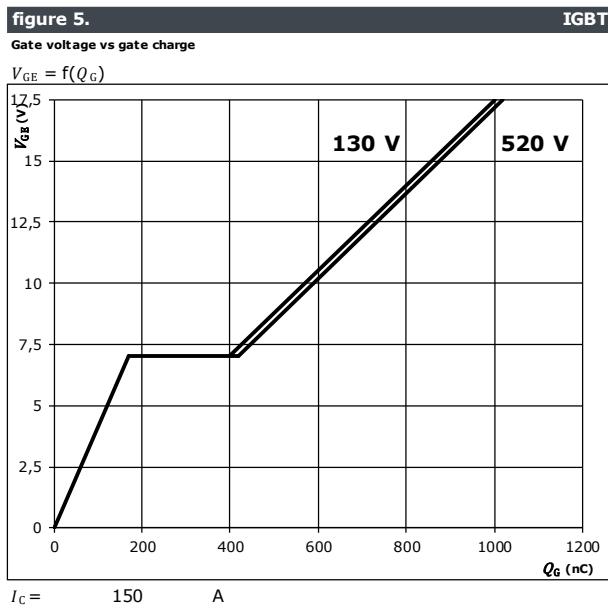
R (K/W)	τ (s)
1,24E-01	1,33E+00
2,59E-01	1,40E-01
1,21E-01	4,38E-02
5,87E-02	9,56E-03
1,74E-02	1,21E-03



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**10-FY07NPA150SM01-L364F08
10-PY07NPA150SM01-L364F08Y**
datasheet

Out. Boost Switch Characteristics

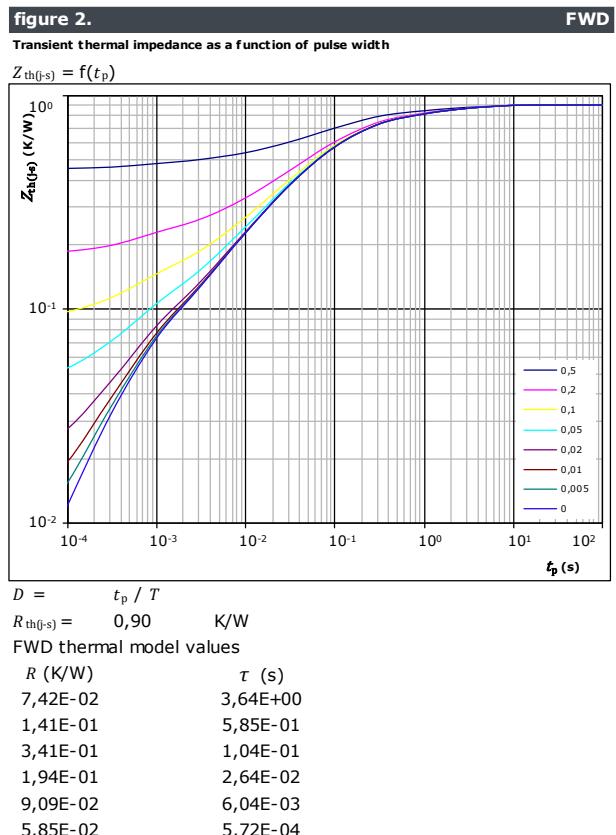
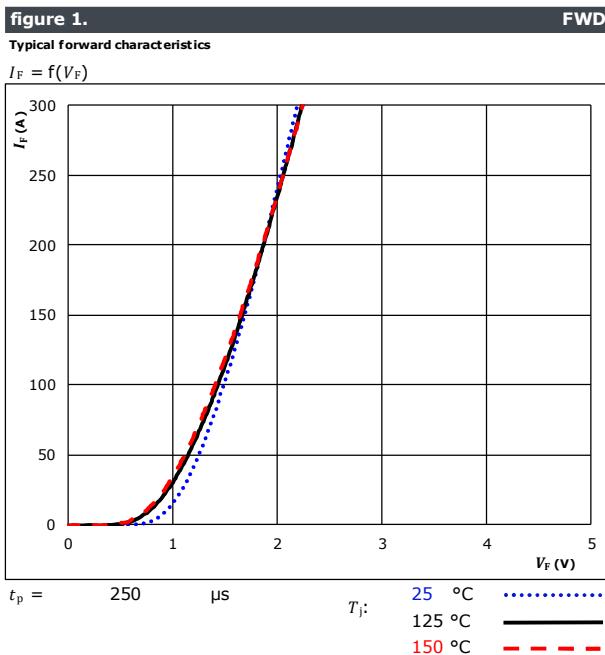




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**10-FY07NPA150SM01-L364F08
10-PY07NPA150SM01-L364F08Y**
datasheet

Out. Boost Diode Characteristics

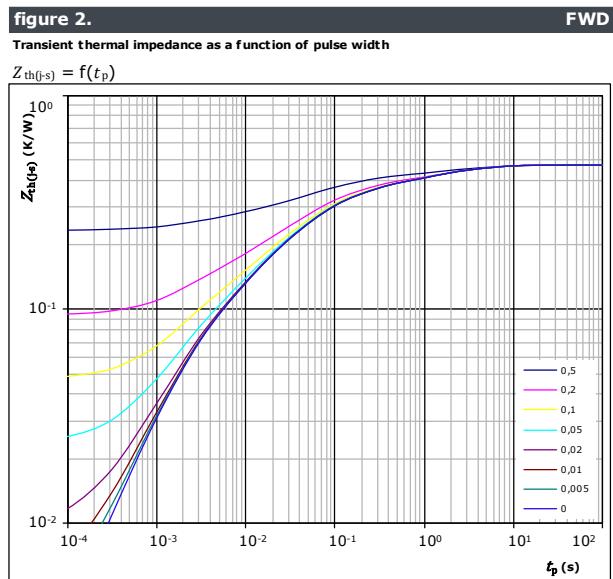
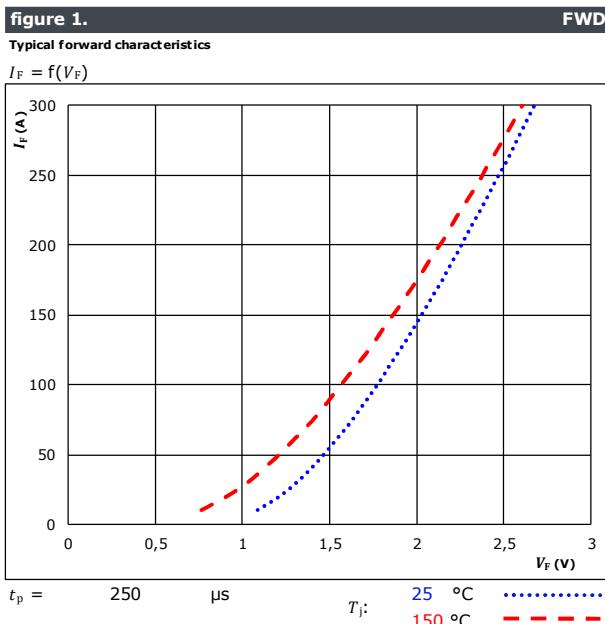




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**10-FY07NPA150SM01-L364F08
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datasheet

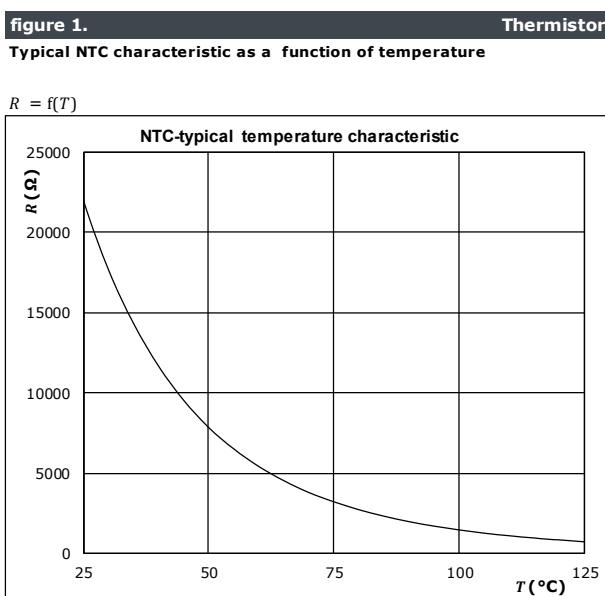
Out. Boost Inverse Diode Characteristics



$D = t_p / T$
 $R_{th(t-s)} = 0,47 \text{ K/W}$
FWD thermal model values

R (K/W)	τ (s)
4,73E-02	4,12E+00
6,76E-02	9,18E-01
1,01E-01	1,37E-01
1,41E-01	3,83E-02
6,28E-02	8,98E-03
4,92E-02	1,99E-03

Thermistor Characteristics





Buck Switching Characteristics

figure 1.

Typical switching energy losses as a function of collector current

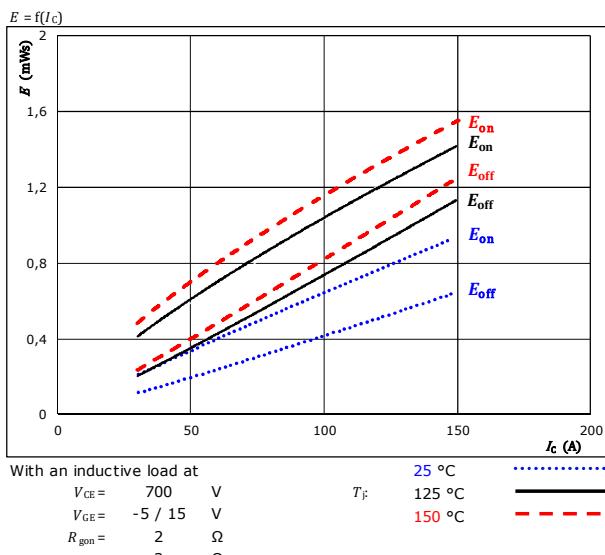


figure 2.

Typical switching energy losses as a function of gate resistor

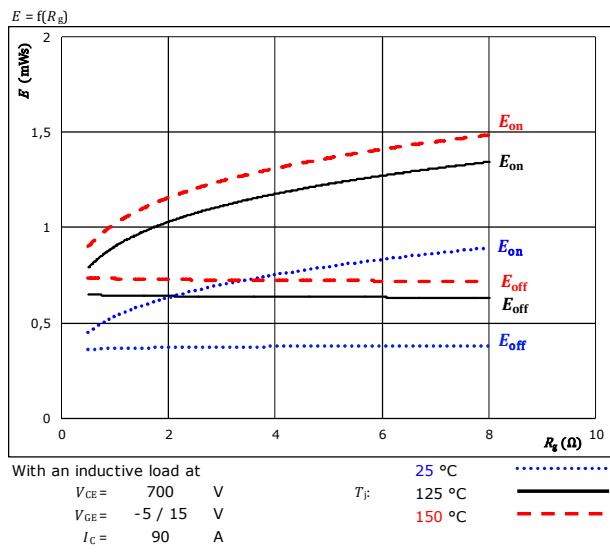


figure 3.

Typical reverse recovered energy loss as a function of collector current

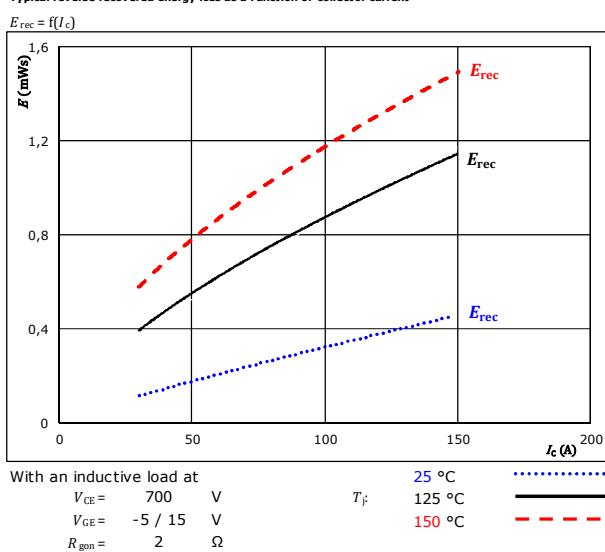
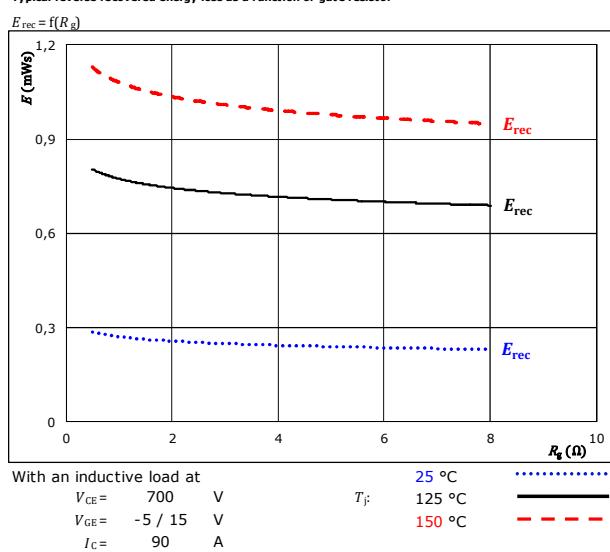


figure 4.

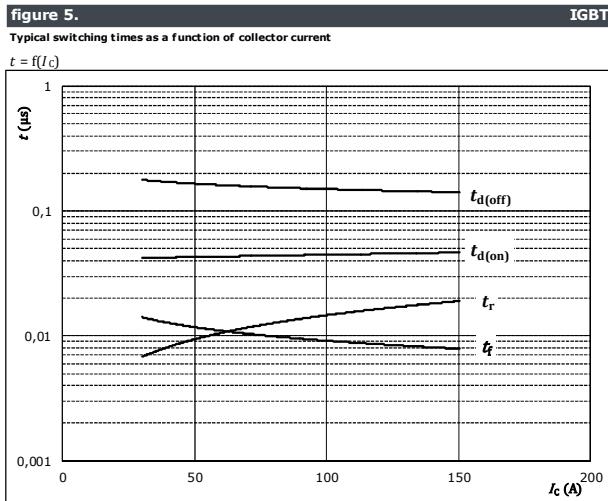
Typical reverse recovered energy loss as a function of gate resistor





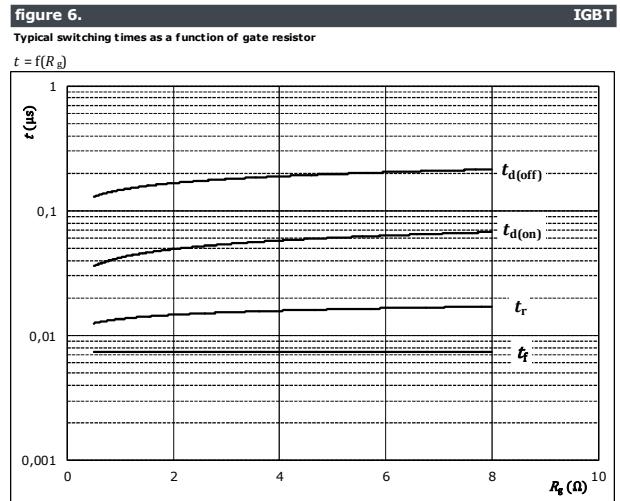
Vincotech

Buck Switching Characteristics



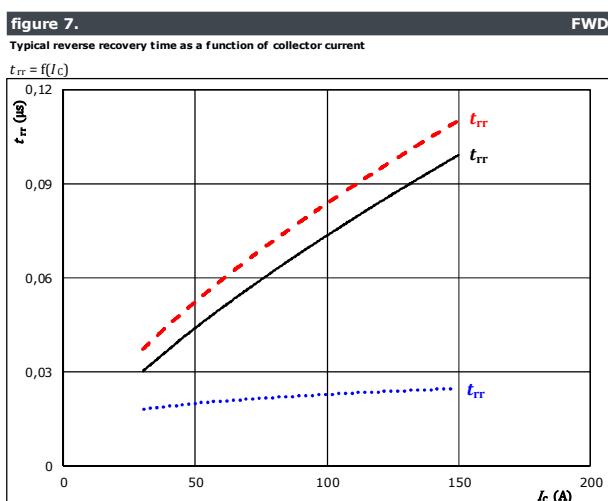
With an inductive load at

$T_J = 150^\circ\text{C}$
 $V_{CE} = 700 \text{ V}$
 $V_{GE} = -5 / 15 \text{ V}$
 $R_{gon} = 2 \Omega$
 $R_{goff} = 2 \Omega$



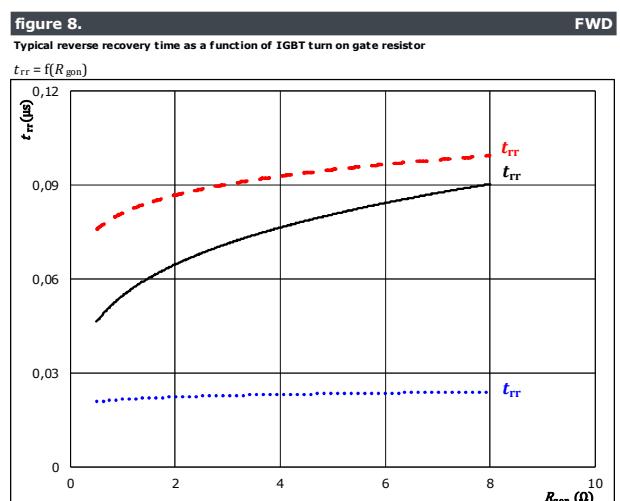
With an inductive load at

$T_J = 150^\circ\text{C}$
 $V_{CE} = 700 \text{ V}$
 $V_{GE} = -5 / 15 \text{ V}$
 $I_C = 90 \text{ A}$



With an inductive load at

$V_{CE} = 700 \text{ V}$ $T_J = 25^\circ\text{C}$ $t_{rr} = 0.03 \mu\text{s}$
 $V_{GE} = -5 / 15 \text{ V}$ $T_J = 125^\circ\text{C}$ $t_{rr} = 0.05 \mu\text{s}$
 $R_{gon} = 2 \Omega$ $T_J = 150^\circ\text{C}$ $t_{rr} = 0.07 \mu\text{s}$



With an inductive load at

$V_{CE} = 700 \text{ V}$ $T_J = 25^\circ\text{C}$ $t_{rr} = 0.03 \mu\text{s}$
 $V_{GE} = -5 / 15 \text{ V}$ $T_J = 125^\circ\text{C}$ $t_{rr} = 0.05 \mu\text{s}$
 $I_C = 90 \text{ A}$ $T_J = 150^\circ\text{C}$ $t_{rr} = 0.07 \mu\text{s}$

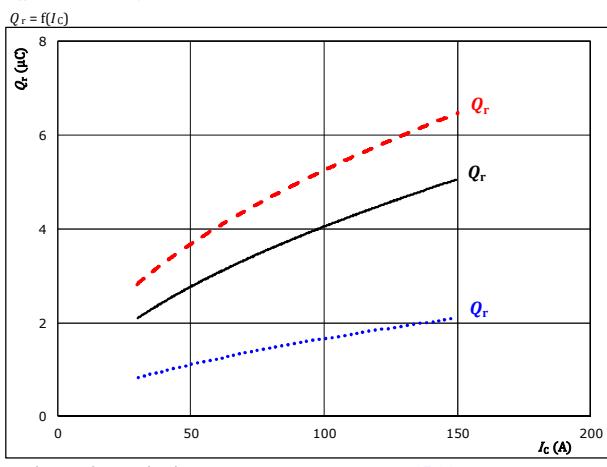


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Buck Switching Characteristics

figure 9.

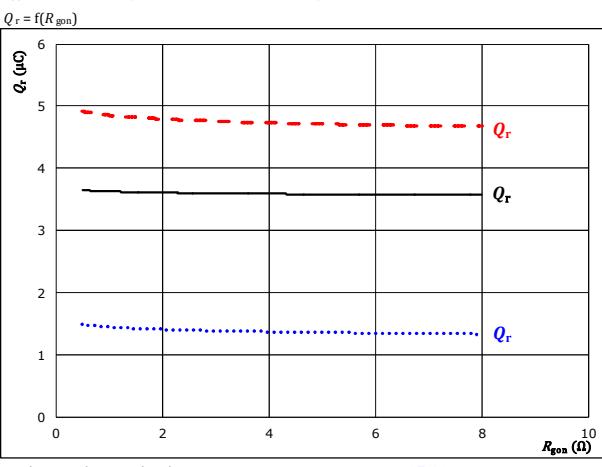
Typical recovered charge as a function of collector current



With an inductive load at
 $V_{CE} = 700$ V $T_f = 25$ °C $R_{gon} = 2$ Ω
 $V_{GE} = -5 / 15$ V $T_f = 125$ °C $V_{GE} = -5 / 15$ V
 $I_C = 90$ A $T_f = 150$ °C

figure 10.

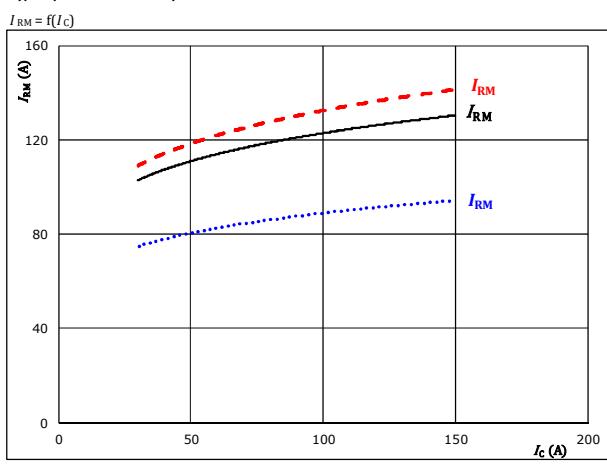
Typical recovered charge as a function of IGBT turn on gate resistor



With an inductive load at
 $V_{CE} = 700$ V $T_f = 25$ °C $I_C = 90$ A
 $V_{GE} = -5 / 15$ V $T_f = 125$ °C $V_{GE} = -5 / 15$ V
 $I_C = 90$ A $T_f = 150$ °C

figure 11.

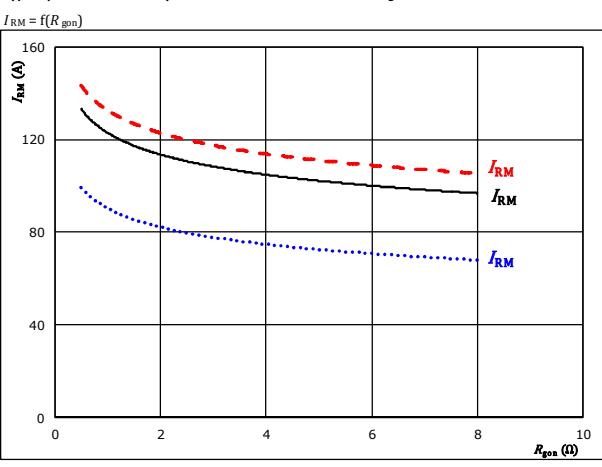
Typical peak reverse recovery current as a function of collector current



With an inductive load at
 $V_{CE} = 700$ V $T_f = 25$ °C $R_{gon} = 2$ Ω
 $V_{GE} = -5 / 15$ V $T_f = 125$ °C $V_{GE} = -5 / 15$ V
 $I_C = 90$ A $T_f = 150$ °C

figure 12.

Typical peak reverse recovery current as a function of IGBT turn on gate resistor



With an inductive load at
 $V_{CE} = 700$ V $T_f = 25$ °C $I_C = 90$ A
 $V_{GE} = -5 / 15$ V $T_f = 125$ °C $V_{GE} = -5 / 15$ V
 $I_C = 90$ A $T_f = 150$ °C



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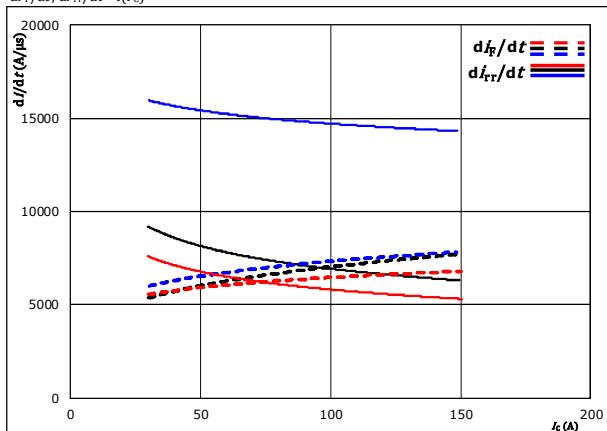
**10-FY07NPA150SM01-L364F08
10-PY07NPA150SM01-L364F08Y**
datasheet

Buck Switching Characteristics

figure 13.

Typical rate of fall of forward and reverse recovery current as a function of collector current

$di_F/dt, di_{rr}/dt = f(I_c)$



With an inductive load at

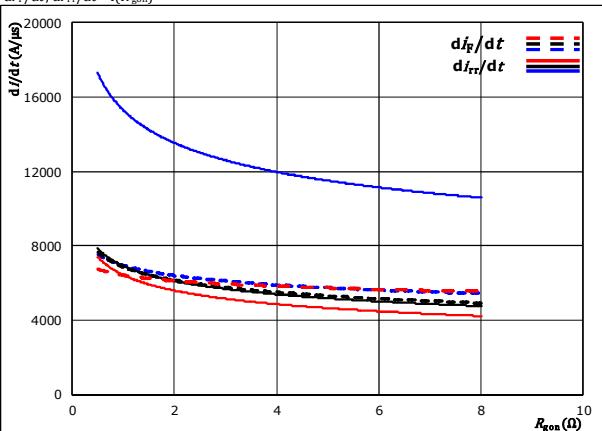
$V_{CE} = 700$ V $T_f = 25$ °C
 $V_{GE} = -5 / 15$ V $T_f = 125$ °C
 $R_{gon} = 2$ Ω $T_f = 150$ °C

FWD

figure 14.

Typical rate of fall of forward and reverse recovery current as a function of IGBT turn on gate resistor

$di_F/dt, di_{rr}/dt = f(R_{gon})$



With an inductive load at

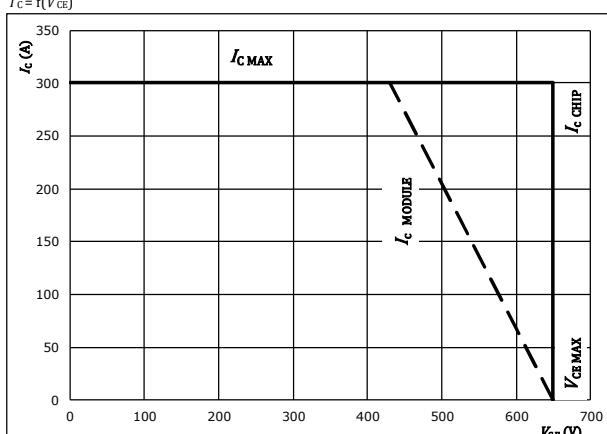
$V_{CE} = 700$ V $T_f = 25$ °C
 $V_{GE} = -5 / 15$ V $T_f = 125$ °C
 $I_c = 90$ A $T_f = 150$ °C

FWD

figure 15.

Reverse bias safe operating area

$I_c = f(V_{CE})$



At

$T_f = 125$ °C
 $R_{gon} = 2$ Ω
 $R_{goff} = 2$ Ω

IGBT



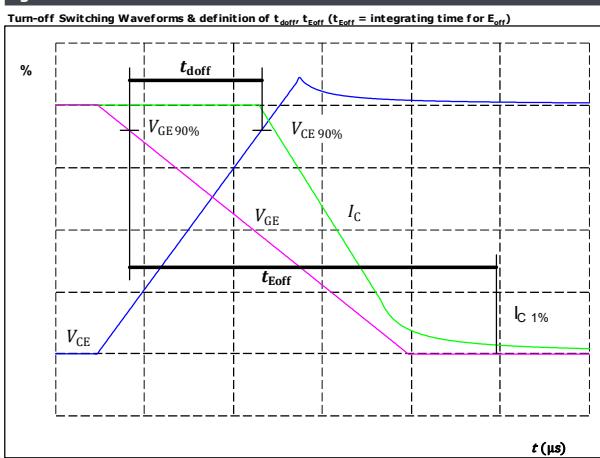
Buck Switching Definitions

General conditions

T_j	=	125 °C
R_{gon}	=	2 Ω
R_{goff}	=	2 Ω

figure 1.

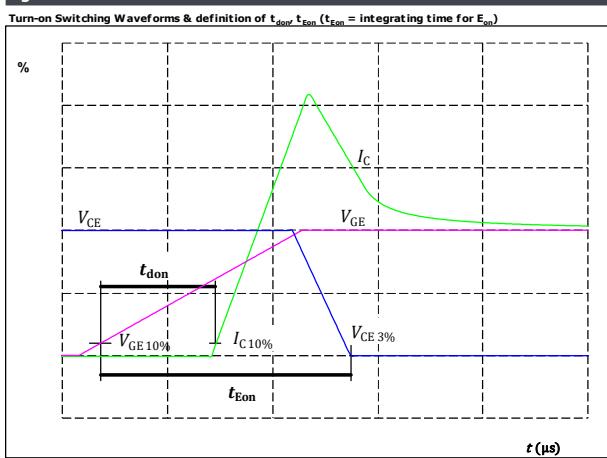
IGBT



$V_{GE}(0\%) = -5 \text{ V}$
 $V_{GE}(100\%) = 15 \text{ V}$
 $V_C(100\%) = 700 \text{ V}$
 $I_C(100\%) = 90 \text{ A}$
 $t_{doff} = 147 \text{ ns}$

figure 2.

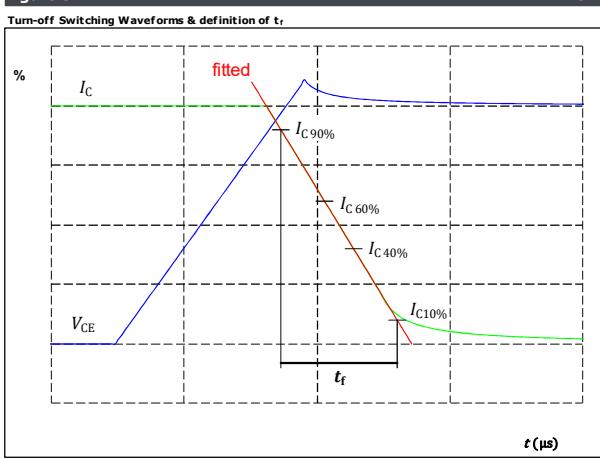
IGBT



$V_{GE}(0\%) = -5 \text{ V}$
 $V_{GE}(100\%) = 15 \text{ V}$
 $V_C(100\%) = 700 \text{ V}$
 $I_C(100\%) = 90 \text{ A}$
 $t_{don} = 46 \text{ ns}$

figure 3.

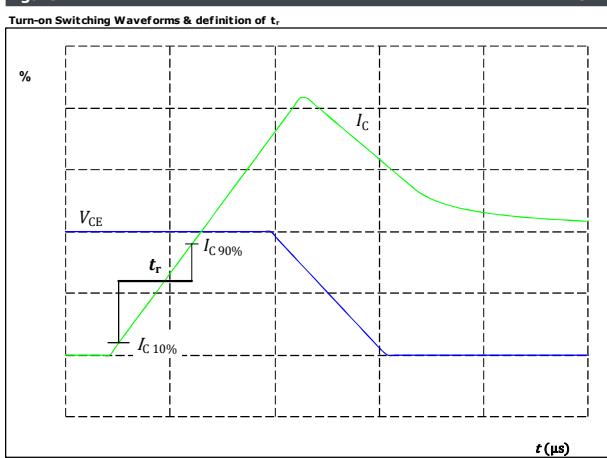
IGBT



$V_C(100\%) = 700 \text{ V}$
 $I_C(100\%) = 90 \text{ A}$
 $t_f = 7 \text{ ns}$

figure 4.

IGBT



$V_C(100\%) = 700 \text{ V}$
 $I_C(100\%) = 90 \text{ A}$
 $t_r = 13 \text{ ns}$



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datasheet

Buck Switching Characteristics

figure 5.

Turn-off Switching Waveforms & definition of t_{rr}

FWD

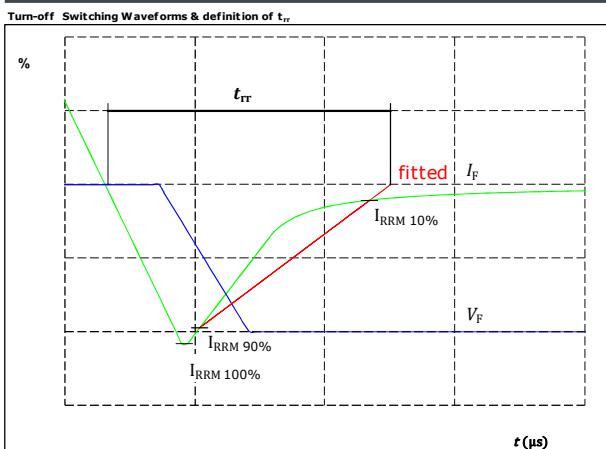
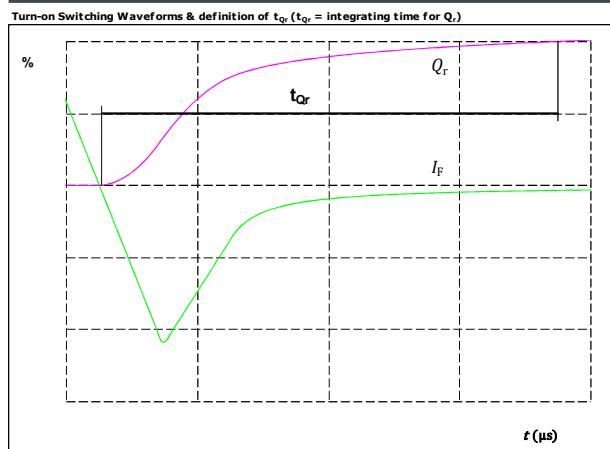


figure 6.

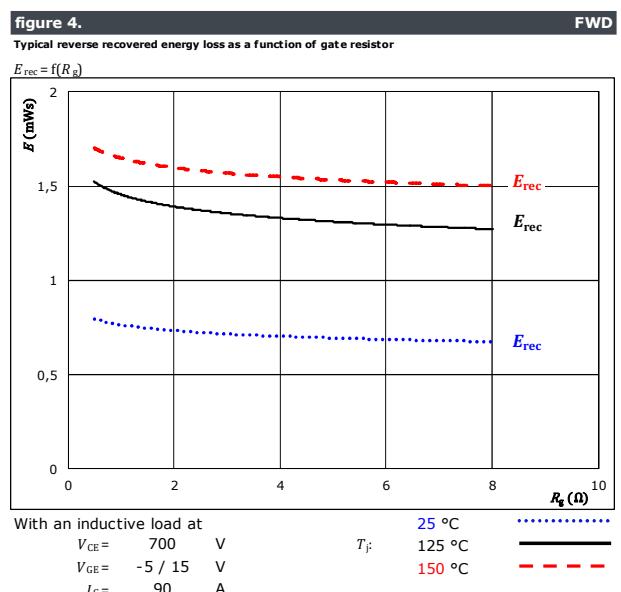
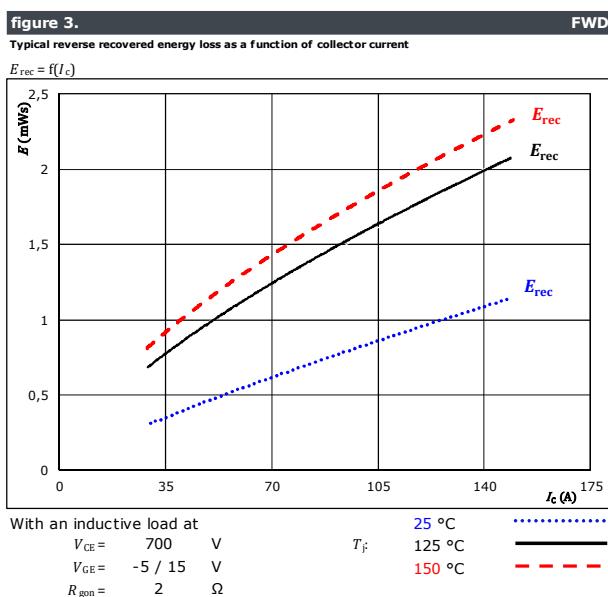
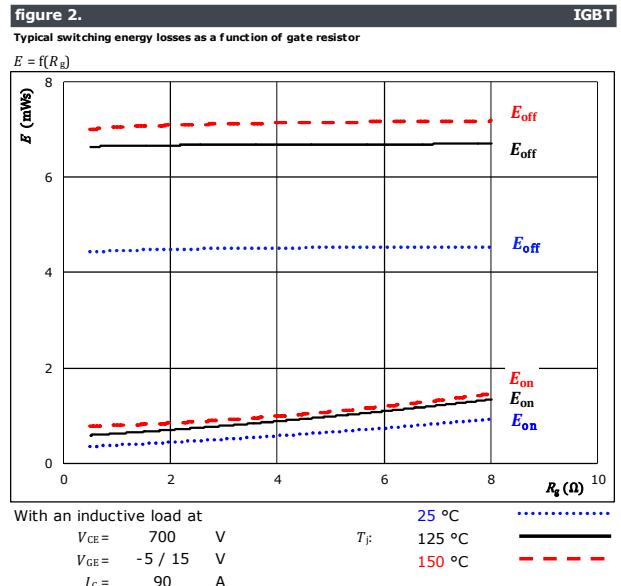
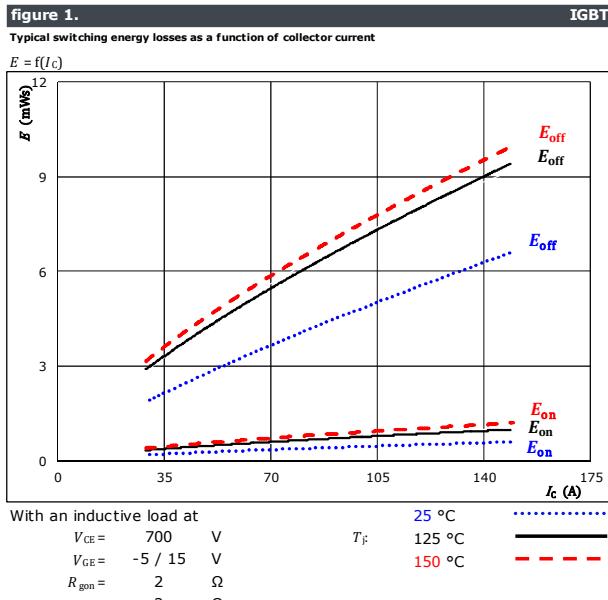
Turn-on Switching Waveforms & definition of t_{qr} (t_{qr} = integrating time for Q_r)

FWD





Boost Switching Characteristics



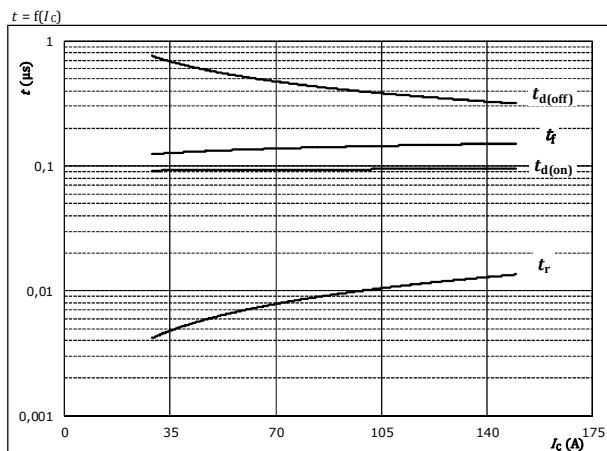


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Boost Switching Characteristics

figure 5. IGBT

Typical switching times as a function of collector current



With an inductive load at

$T_J = 150 \text{ } ^\circ\text{C}$

$V_{CE} = 700 \text{ V}$

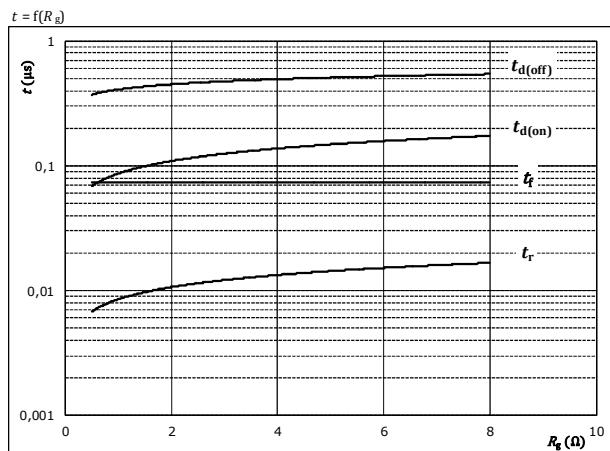
$V_{GE} = -5 / 15 \text{ V}$

$R_{gon} = 2 \Omega$

$R_{goff} = 2 \Omega$

figure 6. IGBT

Typical switching times as a function of gate resistor



With an inductive load at

$T_J = 150 \text{ } ^\circ\text{C}$

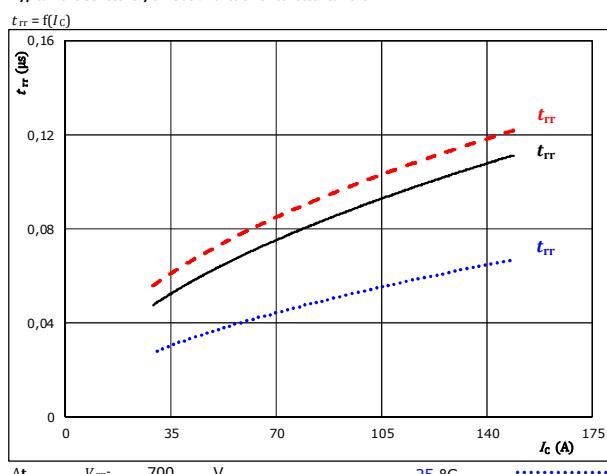
$V_{CE} = 700 \text{ V}$

$V_{GE} = -5 / 15 \text{ V}$

$I_C = 90 \text{ A}$

figure 7. FWD

Typical reverse recovery time as a function of collector current



At

$V_{CE} = 700 \text{ V}$

$V_{GE} = -5 / 15 \text{ V}$

$R_{gon} = 2 \Omega$

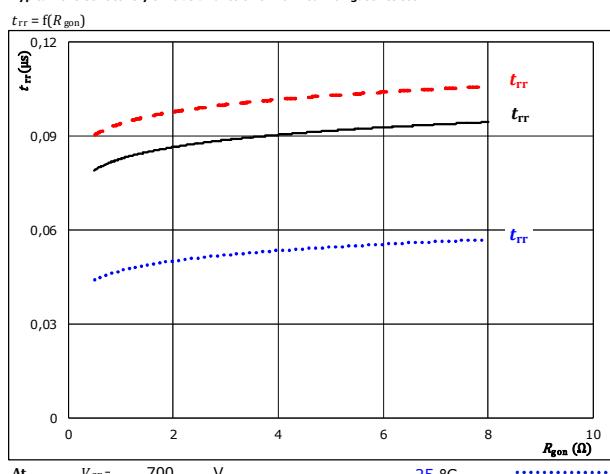
$T_J = 25 \text{ } ^\circ\text{C}$

$T_f = 125 \text{ } ^\circ\text{C}$

$150 \text{ } ^\circ\text{C}$

figure 8. FWD

Typical reverse recovery time as a function of IGBT turn on gate resistor



At

$V_{CE} = 700 \text{ V}$

$V_{GE} = -5 / 15 \text{ V}$

$I_C = 90 \text{ A}$

$T_J = 25 \text{ } ^\circ\text{C}$

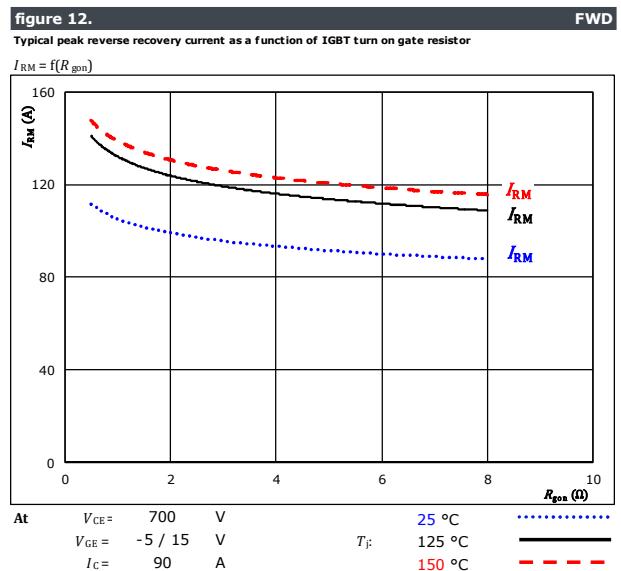
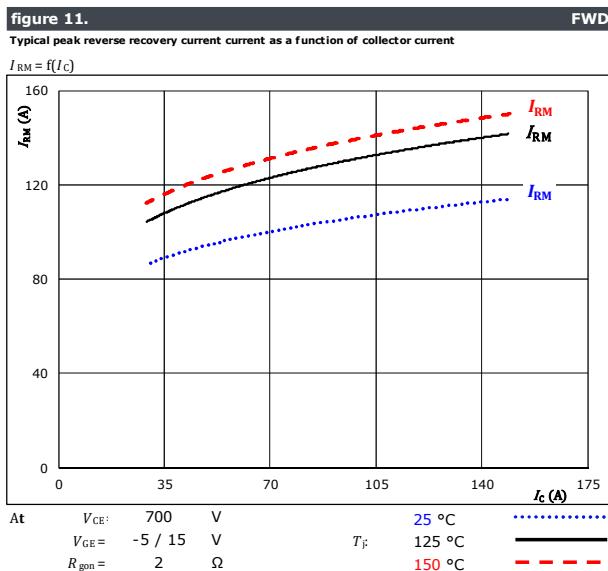
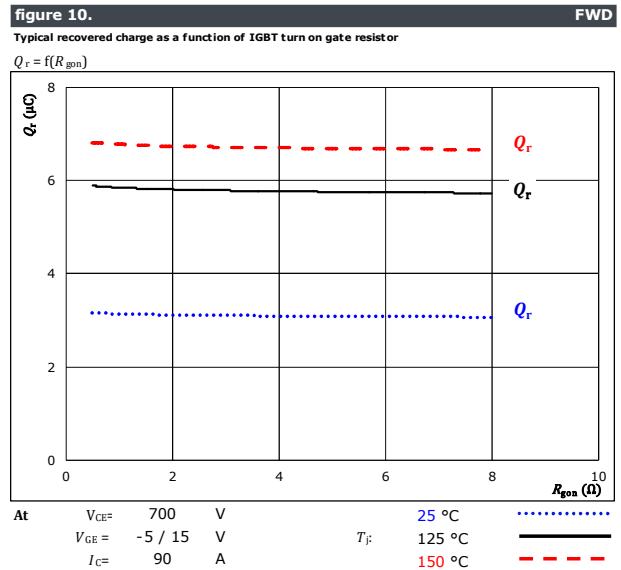
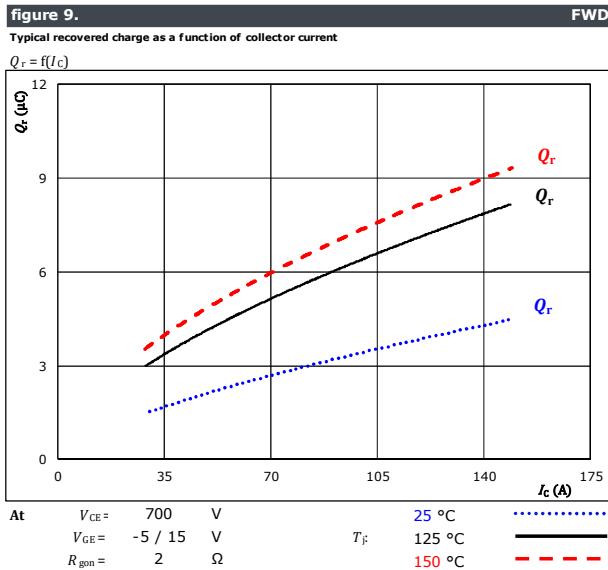
$T_f = 125 \text{ } ^\circ\text{C}$

$150 \text{ } ^\circ\text{C}$



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Boost Switching Characteristics





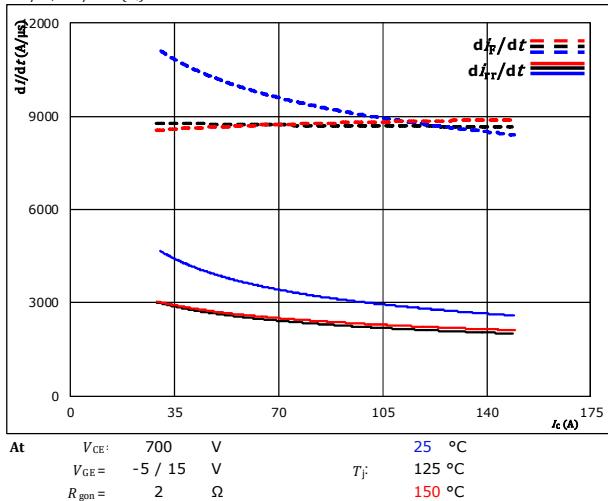
Vincotech

Boost Switching Characteristics

figure 13.

Typical rate of fall of forward and reverse recovery current as a function of collector current

$di_F/dt, di_{rr}/dt = f(I_c)$

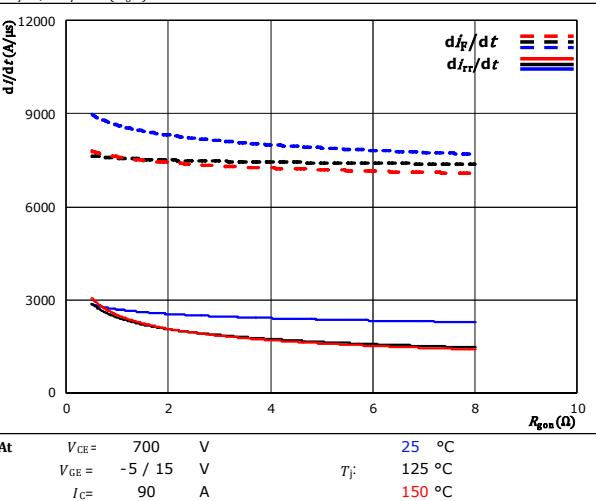


FWD

figure 14.

Typical rate of fall of forward and reverse recovery current as a function of IGBT turn on gate resistor

$di_F/dt, di_{rr}/dt = f(R_{gon})$

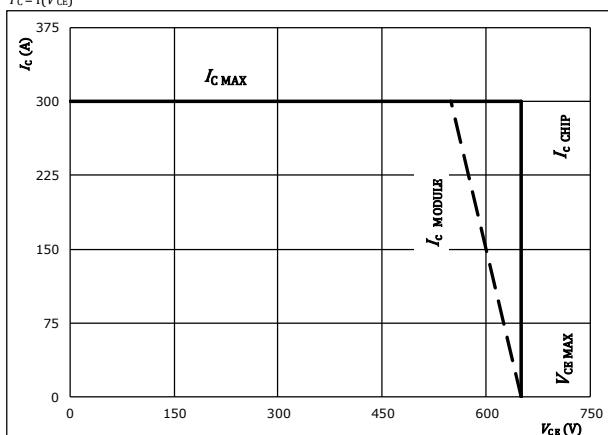


FWD

figure 15.

Reverse bias safe operating area

$I_c = f(V_{CE})$



IGBT



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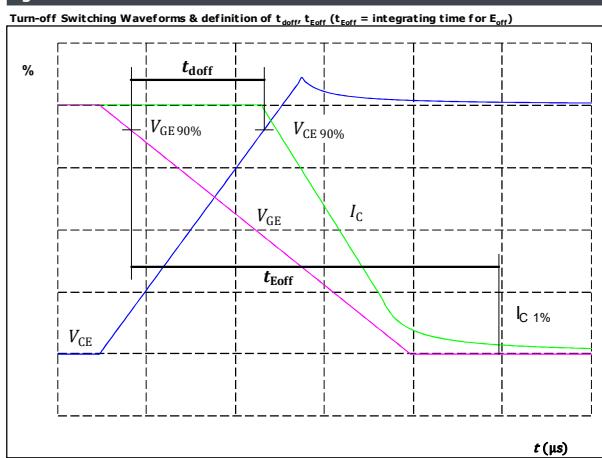
Boost Switching Definitions

General conditions

T_j	=	125 °C
R_{gon}	=	2 Ω
R_{goff}	=	2 Ω

figure 1.

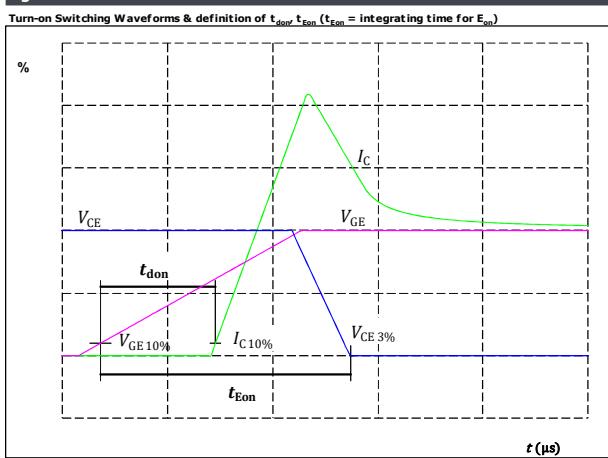
IGBT



$V_{GE}(0\%) =$	-5	V
$V_{GE}(100\%) =$	15	V
$V_C(100\%) =$	700	V
$I_C(100\%) =$	90	A
$t_{doff} =$	397	ns

figure 2.

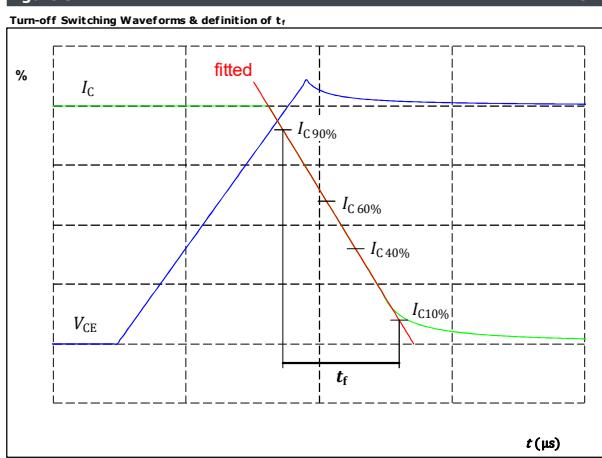
IGBT



$V_{GE}(0\%) =$	-5	V
$V_{GE}(100\%) =$	15	V
$V_C(100\%) =$	700	V
$I_C(100\%) =$	90	A
$t_{don} =$	94	ns

figure 3.

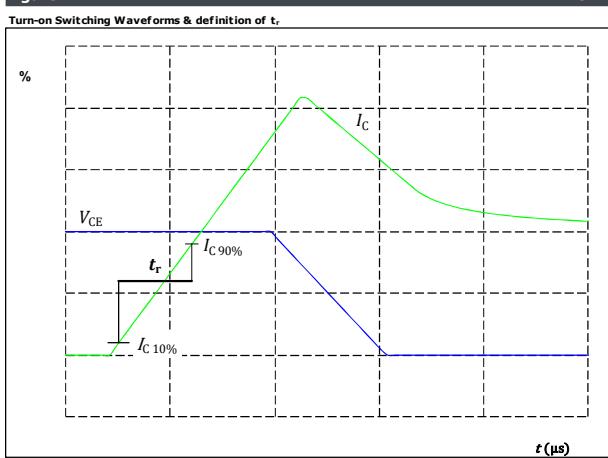
IGBT



$V_C(100\%) =$	700	V
$I_C(100\%) =$	90	A
$t_f =$	73	ns

figure 4.

IGBT



$V_C(100\%) =$	700	V
$I_C(100\%) =$	90	A
$t_r =$	9	ns



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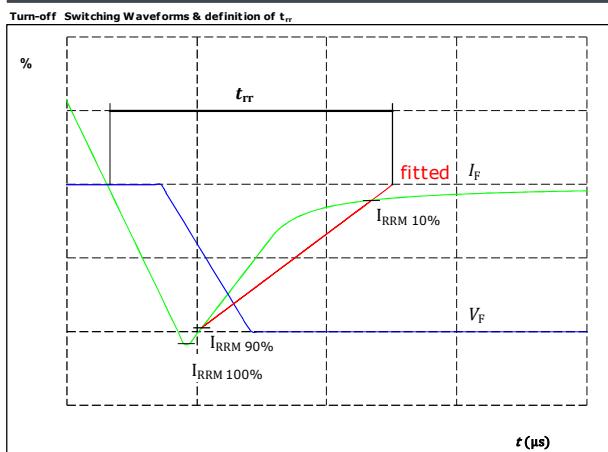
**10-FY07NPA150SM01-L364F08
10-PY07NPA150SM01-L364F08Y**
datasheet

Boost Switching Characteristics

figure 5.

Turn-off Switching Waveforms & definition of t_{rr}

FWD

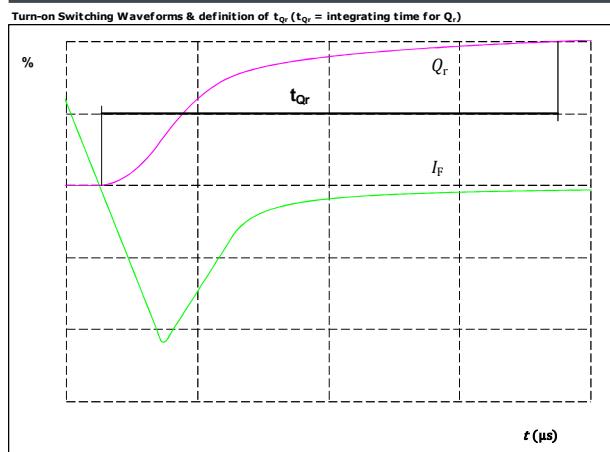


$I_F(100\%) = 700 \text{ V}$
 $I_F(100\%) = 90 \text{ A}$
 $I_{RRM}(100\%) = 130 \text{ A}$
 $t_{rr} = 86 \text{ ns}$

figure 6.

Turn-on Switching Waveforms & definition of t_{qr} (t_{qr} = integrating time for Q_r)

FWD



$I_F(100\%) = 90 \text{ A}$
 $Q_r(100\%) = 5,86 \mu\text{C}$



10-FY07NPA150SM01-L364F08
10-PY07NPA150SM01-L364F08Y
datasheet

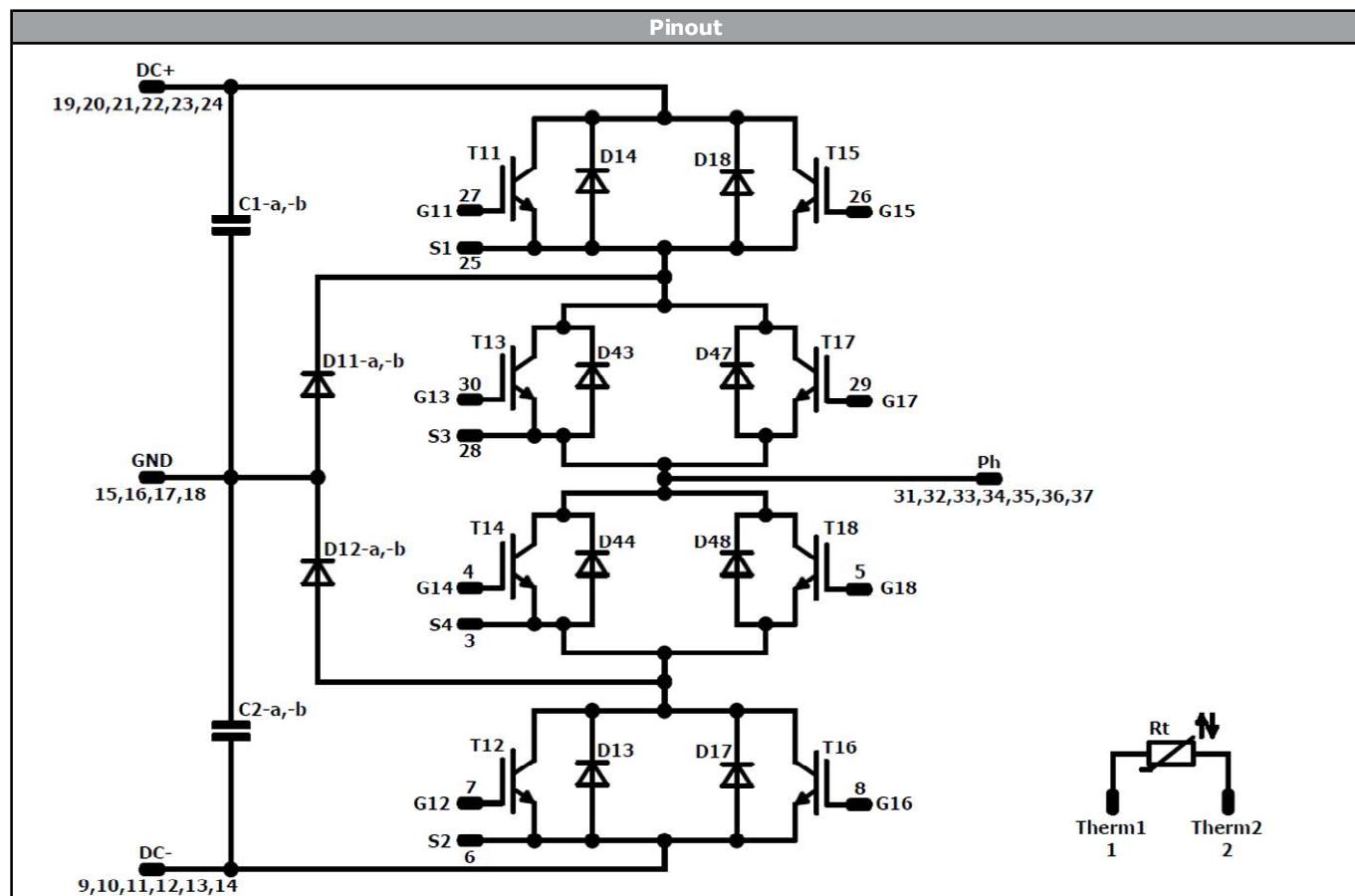
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Ordering Code & Marking							
Version				Ordering Code			
without thermal paste 12mm housing with solder pins				10-FY07NPA150SM01-L364F08			
without thermal paste 12mm housing with press-fit pins				10-PY07NPA150SM01-L364F08Y			
with thermal paste 12mm housing with solder pins				10-FY07NPA150SM01-L364F08-/3/			
with thermal paste 12mm housing with press-fit pins				10-PY07NPA150SM01-L364F08Y-/3/			
NN-NNNNNNNNNNNN TTTTTTVV WWYY UL VIN LLLL SSSS			Text	Name	Date code	UL & VIN	Lot
			NN-NNNNNNNNNNNN-TTTTTVV	WWYY	UL VIN	LLLLL	SSSS
		Datamatrix	Type&Ver	Lot number	Serial	Date code	
			TTTTTTVV	LLLLL	SSSS	WWYY	

Outline																																																																																																																																																															
Pin table				Outline																																																																																																																																																											
<table border="1"><thead><tr><th>Pin</th><th>X</th><th>Y</th><th>Function</th></tr></thead><tbody><tr><td>1</td><td>52,2</td><td>6,9</td><td>Therm1</td></tr><tr><td>2</td><td>52,2</td><td>0</td><td>Therm2</td></tr><tr><td>3</td><td>36,2</td><td>6,75</td><td>S4</td></tr><tr><td>4</td><td>33,2</td><td>7,9</td><td>G14</td></tr><tr><td>5</td><td>33,2</td><td>4,9</td><td>G18</td></tr><tr><td>6</td><td>9,2</td><td>5,75</td><td>S2</td></tr><tr><td>7</td><td>6,2</td><td>6,9</td><td>G12</td></tr><tr><td>8</td><td>6,2</td><td>3,9</td><td>G16</td></tr><tr><td>9</td><td>2,7</td><td>0</td><td>DC-</td></tr><tr><td>10</td><td>0</td><td>0</td><td>DC-</td></tr><tr><td>11</td><td>2,7</td><td>2,7</td><td>DC-</td></tr><tr><td>12</td><td>0</td><td>2,7</td><td>DC-</td></tr><tr><td>13</td><td>2,7</td><td>5,4</td><td>DC-</td></tr><tr><td>14</td><td>0</td><td>5,4</td><td>DC-</td></tr><tr><td>15</td><td>2,7</td><td>12,75</td><td>GND</td></tr><tr><td>16</td><td>0</td><td>12,75</td><td>GND</td></tr><tr><td>17</td><td>2,7</td><td>15,45</td><td>GND</td></tr><tr><td>18</td><td>0</td><td>15,45</td><td>GND</td></tr><tr><td>19</td><td>2,7</td><td>22,8</td><td>DC+</td></tr><tr><td>20</td><td>0</td><td>22,8</td><td>DC+</td></tr><tr><td>21</td><td>2,7</td><td>25,5</td><td>DC+</td></tr><tr><td>22</td><td>0</td><td>25,5</td><td>DC+</td></tr><tr><td>23</td><td>2,7</td><td>28,2</td><td>DC+</td></tr><tr><td>24</td><td>0</td><td>28,2</td><td>DC+</td></tr><tr><td>25</td><td>18,3</td><td>22,45</td><td>S1</td></tr><tr><td>26</td><td>21,3</td><td>21,3</td><td>G15</td></tr><tr><td>27</td><td>21,3</td><td>24,3</td><td>G11</td></tr><tr><td>28</td><td>43</td><td>22,15</td><td>S3</td></tr><tr><td>29</td><td>46</td><td>21</td><td>G17</td></tr><tr><td>30</td><td>46</td><td>24</td><td>G13</td></tr><tr><td>31</td><td>52,2</td><td>20,1</td><td>Ph</td></tr><tr><td>32</td><td>49,5</td><td>22,8</td><td>Ph</td></tr><tr><td>33</td><td>52,2</td><td>22,8</td><td>Ph</td></tr><tr><td>34</td><td>49,5</td><td>25,5</td><td>Ph</td></tr><tr><td>35</td><td>52,2</td><td>25,5</td><td>Ph</td></tr><tr><td>36</td><td>49,5</td><td>28,2</td><td>Ph</td></tr><tr><td>37</td><td>52,2</td><td>28,2</td><td>Ph</td></tr></tbody></table>				Pin	X	Y	Function	1	52,2	6,9	Therm1	2	52,2	0	Therm2	3	36,2	6,75	S4	4	33,2	7,9	G14	5	33,2	4,9	G18	6	9,2	5,75	S2	7	6,2	6,9	G12	8	6,2	3,9	G16	9	2,7	0	DC-	10	0	0	DC-	11	2,7	2,7	DC-	12	0	2,7	DC-	13	2,7	5,4	DC-	14	0	5,4	DC-	15	2,7	12,75	GND	16	0	12,75	GND	17	2,7	15,45	GND	18	0	15,45	GND	19	2,7	22,8	DC+	20	0	22,8	DC+	21	2,7	25,5	DC+	22	0	25,5	DC+	23	2,7	28,2	DC+	24	0	28,2	DC+	25	18,3	22,45	S1	26	21,3	21,3	G15	27	21,3	24,3	G11	28	43	22,15	S3	29	46	21	G17	30	46	24	G13	31	52,2	20,1	Ph	32	49,5	22,8	Ph	33	52,2	22,8	Ph	34	49,5	25,5	Ph	35	52,2	25,5	Ph	36	49,5	28,2	Ph	37	52,2	28,2	Ph				
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9	2,7	0	DC-																																																																																																																																																												
10	0	0	DC-																																																																																																																																																												
11	2,7	2,7	DC-																																																																																																																																																												
12	0	2,7	DC-																																																																																																																																																												
13	2,7	5,4	DC-																																																																																																																																																												
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15	2,7	12,75	GND																																																																																																																																																												
16	0	12,75	GND																																																																																																																																																												
17	2,7	15,45	GND																																																																																																																																																												
18	0	15,45	GND																																																																																																																																																												
19	2,7	22,8	DC+																																																																																																																																																												
20	0	22,8	DC+																																																																																																																																																												
21	2,7	25,5	DC+																																																																																																																																																												
22	0	25,5	DC+																																																																																																																																																												
23	2,7	28,2	DC+																																																																																																																																																												
24	0	28,2	DC+																																																																																																																																																												
25	18,3	22,45	S1																																																																																																																																																												
26	21,3	21,3	G15																																																																																																																																																												
27	21,3	24,3	G11																																																																																																																																																												
28	43	22,15	S3																																																																																																																																																												
29	46	21	G17																																																																																																																																																												
30	46	24	G13																																																																																																																																																												
31	52,2	20,1	Ph																																																																																																																																																												
32	49,5	22,8	Ph																																																																																																																																																												
33	52,2	22,8	Ph																																																																																																																																																												
34	49,5	25,5	Ph																																																																																																																																																												
35	52,2	25,5	Ph																																																																																																																																																												
36	49,5	28,2	Ph																																																																																																																																																												
37	52,2	28,2	Ph																																																																																																																																																												



Vincotech



Identification					
ID	Component	Voltage	Current	Function	Comment
T11, T12, T15, T16	IGBT	650V	75A	Buck Switch	
D11, D12	FWD	650V	100A	Buck Diode	
T13, T14, T17, T18	IGBT	650V	75A	Out. Boost Switch	
D13, D14, D17, D18	FWD	650V	50A	Out. Boost Diode	
D43, D44, D47, D48	FWD	650V	50A	Out. Boost Inverse Diode	
C1, C2	Capacitor	630V	-	DC Link Capacitor	
Rt	NTC	-	-	Thermistor	



10-FY07NPA150SM01-L364F08
10-PY07NPA150SM01-L364F08Y
datasheet

Vincotech

Packaging instruction			
Standard packaging quantity (SPQ) 100	>SPQ	Standard	<SPQ Sample

Handling instruction			
Handling instructions for if no series packaging available packages see vincotech.com website.			

Package data			
Package data for if no series packaging available packages see vincotech.com website.			

UL recognition and file number			
This device is certified according to UL 1557 standard, UL file number E192116. For more information see vincotech.com website.			

Document No.:	Date:	Modification:	Pages
10-xY07NPA150SM01-L364F08x-D6-14	01 Mar. 2019	Correction of I_c/I_f values	1,2

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As used herein:

1. Life support devices or systems are devices or systems which, (a) are intended for surgical implant into the body, or (b) support or sustain life, or (c) whose failure to perform when properly used in accordance with instructions for use provided in labelling can be reasonably expected to result in significant injury to the user.
2. A critical component is any component of a life support device or system whose failure to perform can be reasonably expected to cause the failure of the life support device or system, or to affect its safety or effectiveness.